

SKKT 323; SKKH 323



SEMIPACK® 3

Thyristor / Diode Modules

SKKT 323

SKKH 323

Features

- Industrial standard package
- Electrically insulated base plate
- Heat transfer through aluminium oxide ceramic insulated metal base plate
- Chip soldered on direct copper bonded Al₂O₃ ceramic
- Thyristor chip with center gate
- UL recognition applied for file no. E63532

Typical Applications*

- DC motor control (e. g. for machine tools)
- Temperature control (e. g. for ovens, chemical processes)
- Professional light dimming (studios, theaters)

1) See the assembly instructions

V_{RSM} V	V_{RRM}, V_{DRM} V	$I_{TRMS} = 520$ A (maximum value for continuous operation) $I_{TAV} = 323$ A (sin. 180; $T_c = 84$ °C)		
1300	1200	SKKT 323/12E	SKKH 323/12E	
1700	1600	SKKT 323/16E	SKKH 323/16E	

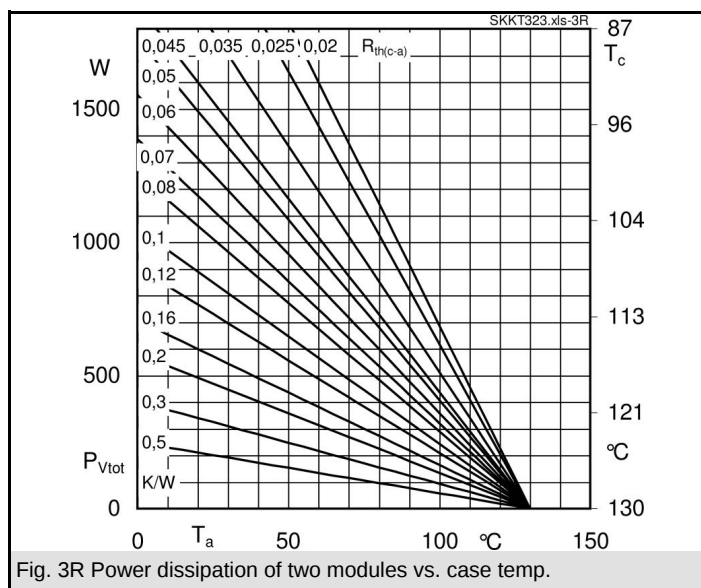
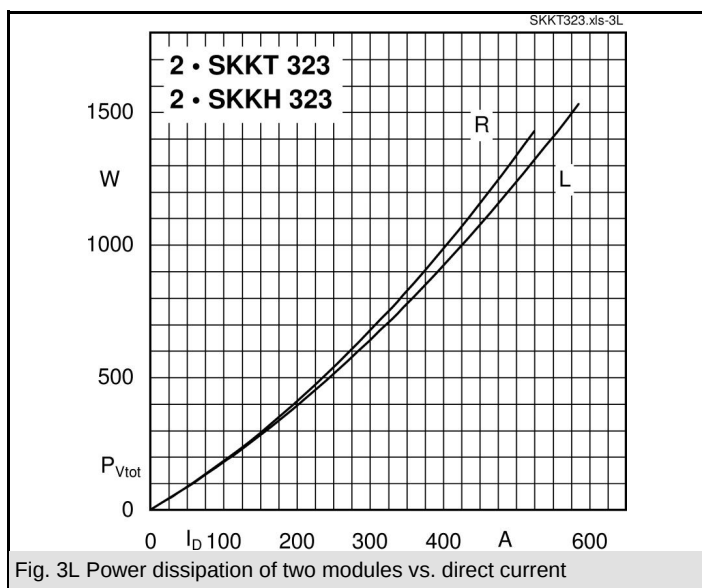
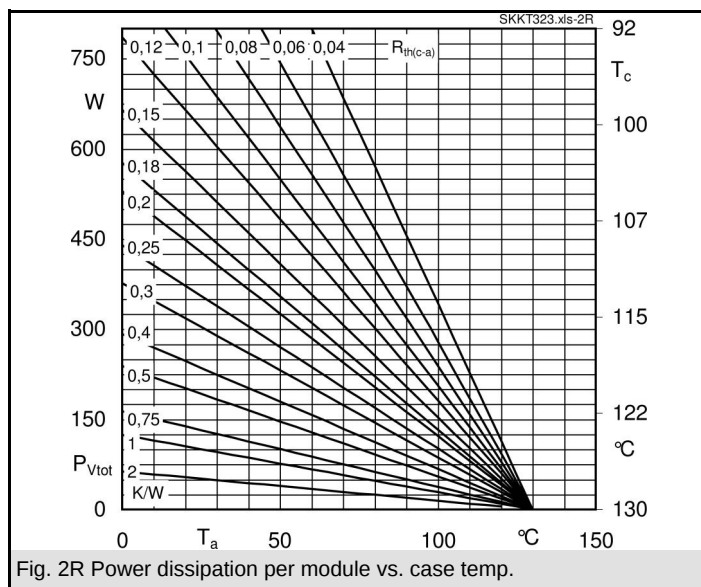
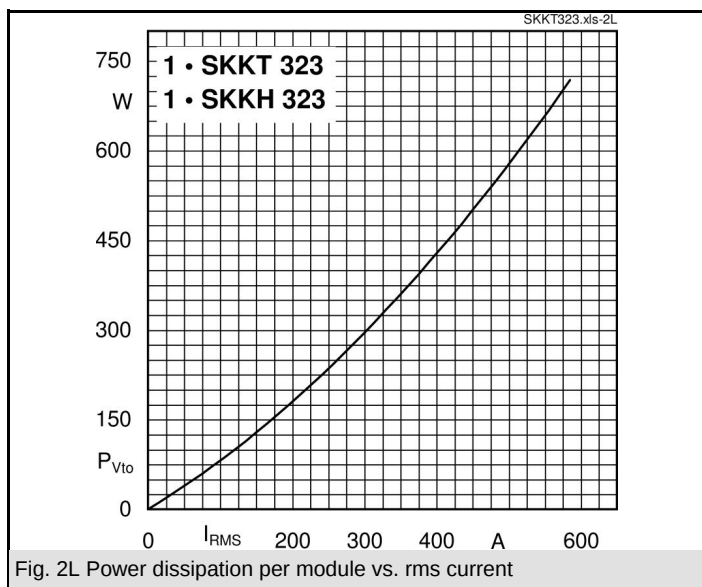
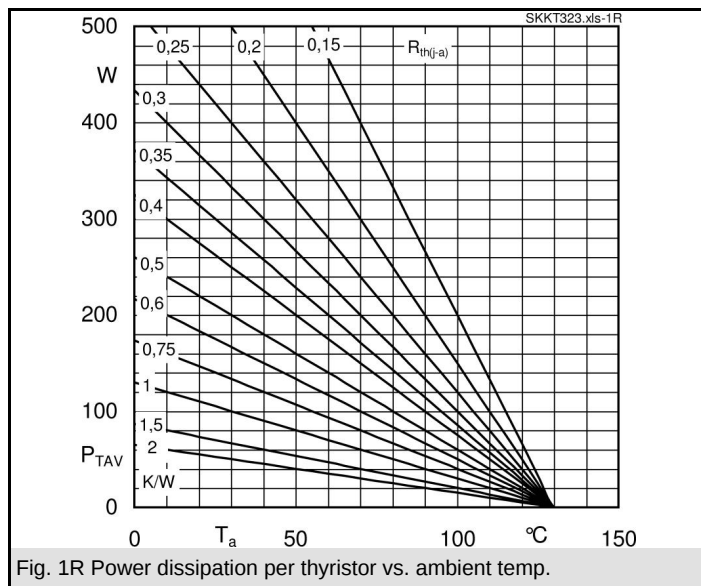
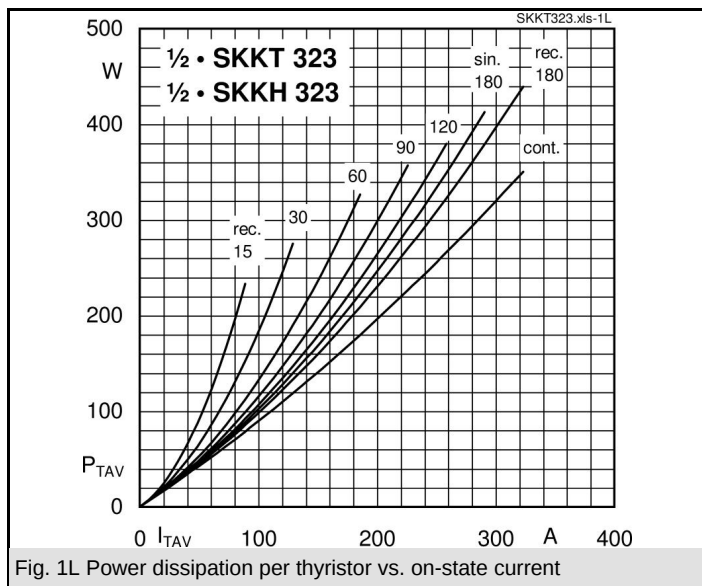
Symbol	Conditions	Values	Units
I_{TAV}	sin. 180; $T_c = 85$ (100) °C;	320 (241)	A
I_{TSM}	$T_{vj} = 25$ °C; 10 ms $T_{vj} = 130$ °C; 10 ms	9500 8200	A A
i^2t	$T_{vj} = 25$ °C; 8,3 ... 10 ms $T_{vj} = 130$ °C; 8,3 ... 10 ms	450000 336000	A ² s A ² s
V_T	$T_{vj} = 25$ °C; $I_T = 750$ A	max. 1,45	V
$V_{T(TO)}$	$T_{vj} = 130$ °C	max. 0,81	V
r_T	$T_{vj} = 130$ °C	max. 0,85	mΩ
I_{DD}, I_{RD}	$T_{vj} = 130$ °C; $V_{RD} = V_{RRM}, V_{DD} = V_{DRM}$	max. 100	mA
t_{gd}	$T_{vj} = 25$ °C; $I_G = 1$ A; $di_G/dt = 1$ A/μs	1	μs
t_{gr}	$V_D = 0,67 * V_{DRM}$	2	μs
$(di/dt)_{cr}$	$T_{vj} = 130$ °C	max. 130	A/μs
$(dv/dt)_{cr}$	$T_{vj} = 130$ °C	max. 1000	V/μs
t_q	$T_{vj} = 130$ °C, typ.	150	μs
I_H	$T_{vj} = 25$ °C; typ. / max.	150 / 500	mA
I_L	$T_{vj} = 25$ °C; $R_G = 33$ Ω; typ. / max.	300 / 2000	mA
V_{GT}	$T_{vj} = 25$ °C; d.c.	min. 2	V
I_{GT}	$T_{vj} = 25$ °C; d.c.	min. 150	mA
V_{GD}	$T_{vj} = 130$ °C; d.c.	max. 0,25	V
I_{GD}	$T_{vj} = 130$ °C; d.c.	max. 10	mA
$R_{th(j-c)}$	cont.; per thyristor / per module	0,091 / 0,0455	K/W
$R_{th(j-c)}$	sin. 180; per thyristor / per module	0,095 / 0,0475	K/W
$R_{th(j-c)}$	rec. 120; per thyristor / per module	0,11 / 0,055	K/W
$R_{th(c-s)}$	per thyristor / per module	0,08 / 0,04	K/W
T_{vj}		- 40 ... + 130	°C
T_{stg}		- 40 ... + 125	°C
V_{isol}	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3600 / 3000	V~
M_s	to heatsink	5 ± 15 % ¹⁾	Nm
M_t	to terminals	9 ± 15 %	Nm
a		5 * 9,81	m/s ²
m	approx.	410	g
Case	SKKT SKKH	A 43a A 56a	



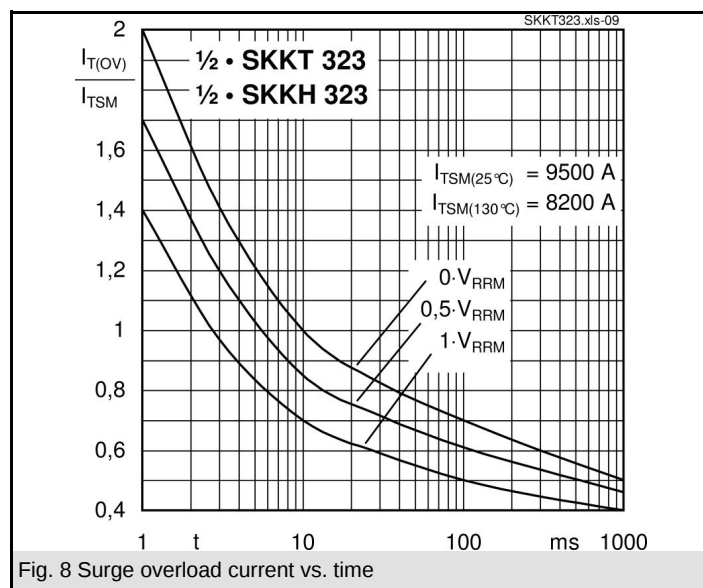
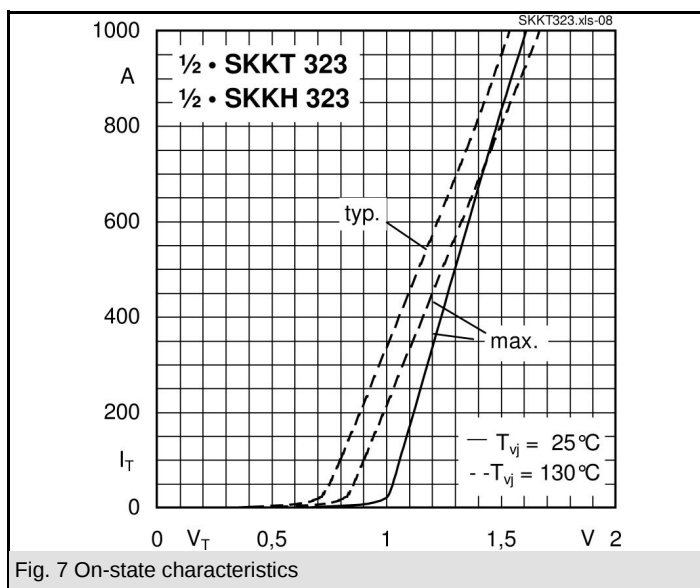
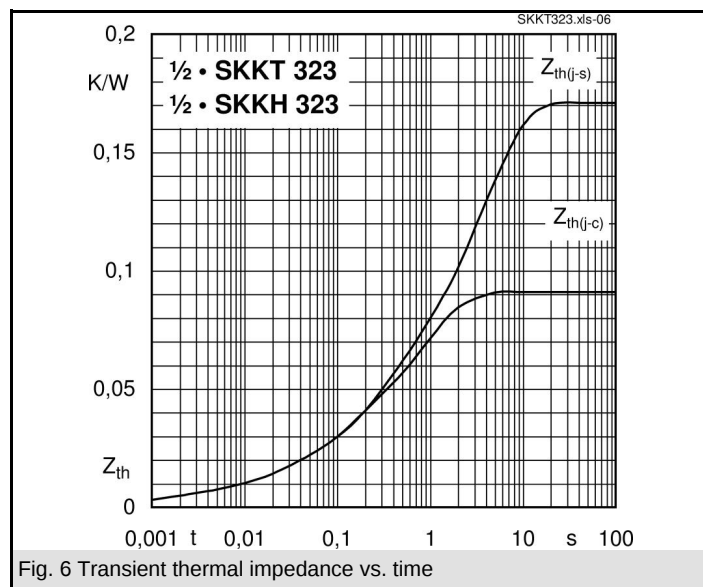
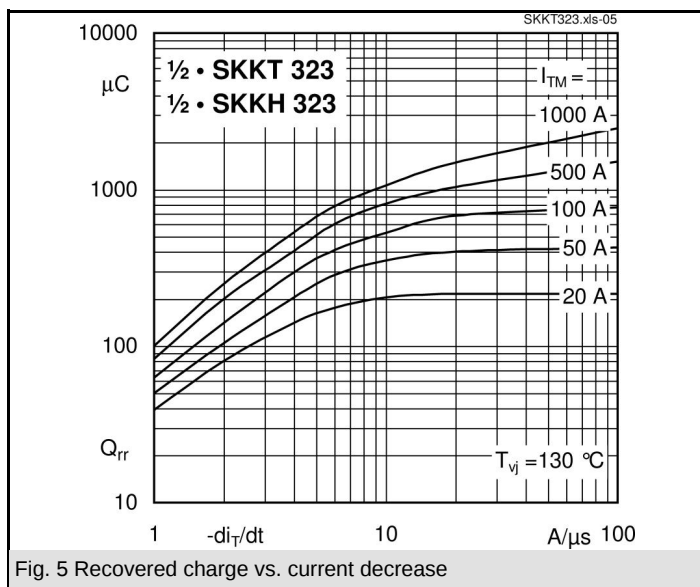
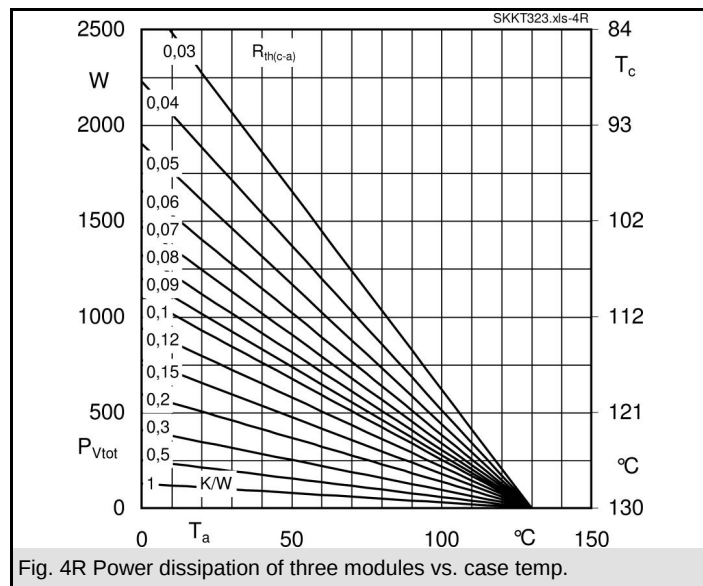
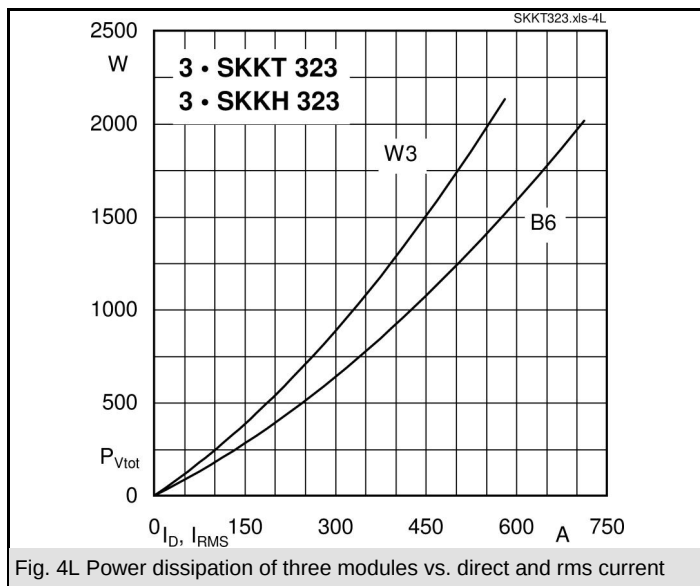
SKKT

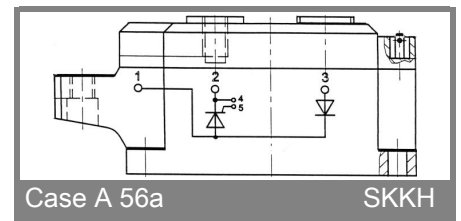
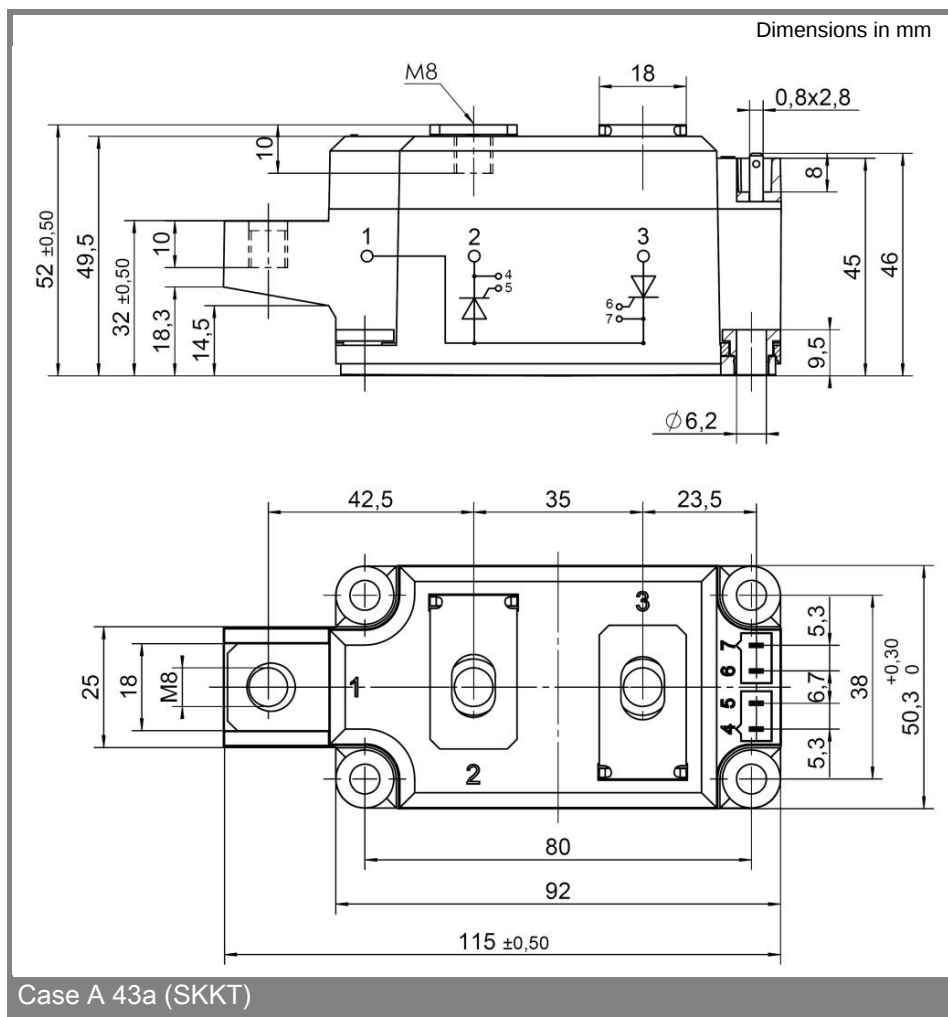
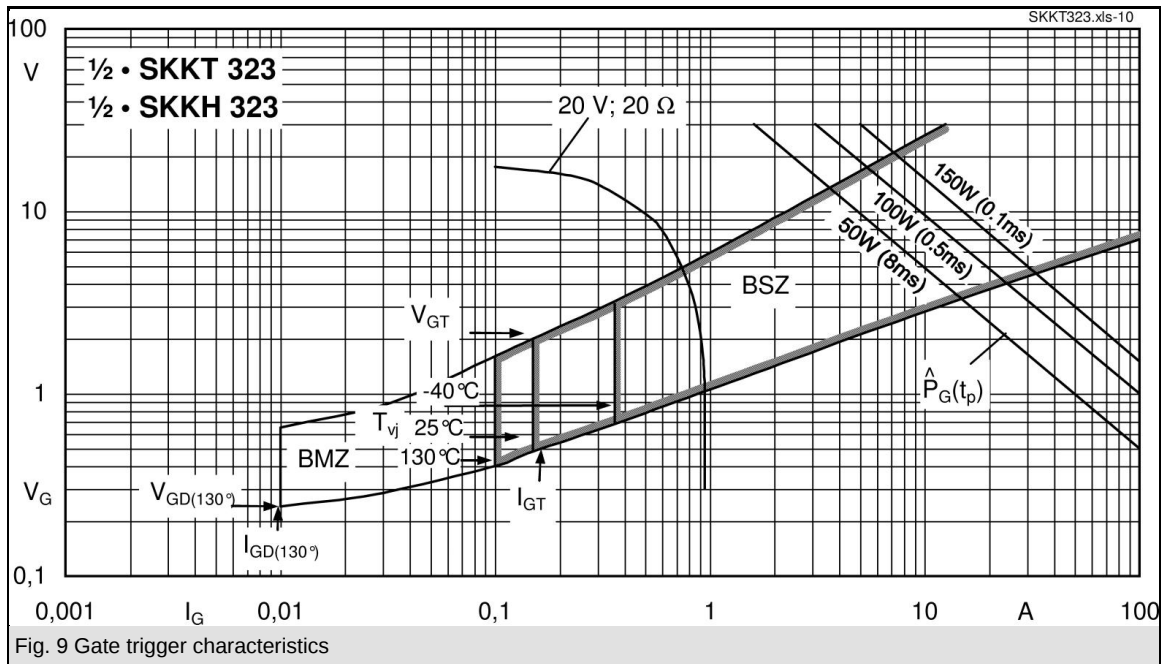


SKKH



SKKT 323; SKKH 323





* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We

therefore strongly recommend prior consultation of our staff.